

PNP General-Purpose Transistor, 60 V

PN2907A

Description

The PN2907A is 60 V PNP bipolar transistor designed for use as a general-purpose amplifier or switch in applications that require up to 500 mA. The NPN complementary type is the PN2222A.

Features

- High DC Current Gain (h_{FE}) Range: 100 ~ 300
- High-Current Gain Bandwidth Product (f_T): 200 MHz (Minimum)
- Maximum Turn-On Time (t_{on}): 45 ns
- Maximum Turn-Off Time (t_{off}): 100 ns
- This is a Pb-Free Device

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 1, 2)

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{CBO}	Collector-Base Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5.0	V
I_C	Collector Current - Continuous	-800	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

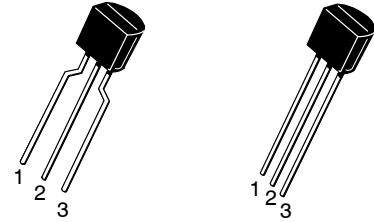
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Max (Note 3)	Unit
P_D	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^\circ\text{C}/\text{W}$

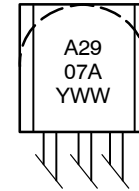
3. PCB size: FR-4 $76 \times 114 \times 1.57 \text{ mm}^3$ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



TO-92 3 4.825x4.76
LEADFORMER
CASE 135AR

TO-92 3 4.825x4.76
CASE 135AN

MARKING DIAGRAM



- 2907A = Specific Device Code
- A = Assembly Site
- Y = Year of Production
- WW = Work Week Number

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

PN2907A

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Max	Unit
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (Note 4)	$I_C = -10\text{ mA}, I_B = 0$	-60	-	V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -10\text{ }\mu\text{A}, I_E = 0$	-60	-	V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -10\text{ }\mu\text{A}, I_C = 0$	-5.0	-	V
I_{BL}	Base Cut-Off Current	$V_{CE} = -30\text{ V}, V_{EB} = -0.5\text{ V}$	-	-50	nA
I_{CEX}	Collector Cut-Off Current	$V_{CE} = -30\text{ V}, V_{EB} = -0.5\text{ V}$	-	-50	nA
I_{CBO}	Collector Cut-Off Current	$V_{CB} = -50\text{ V}, I_E = 0$	-	-0.02	μA
		$V_{CB} = -50\text{ V}, I_E = 0, T_A = 150^\circ\text{C}$	-	-20	

ON CHARACTERISTICS

h_{FE}	DC Current Gain	$I_C = -0.1\text{ mA}, V_{CE} = -10\text{ V}$	75	-	
		$I_C = -1.0\text{ mA}, V_{CE} = -10\text{ V}$	100	-	
		$I_C = -10\text{ mA}, V_{CE} = -10\text{ V}$	100	-	
		$I_C = -150\text{ mA}, V_{CE} = -10\text{ V}$ (Note 4)	100	300	
		$I_C = -500\text{ mA}, V_{CE} = -10\text{ V}$ (Note 4)	50	-	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage (Note 4)	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$	-	-0.4	V
		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$	-	-1.6	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$ (Note 4)	-	-1.3	V
		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$	-	-2.6	

SMALL SIGNAL CHARACTERISTICS

f_T	Current Gain – Bandwidth Product	$I_C = -50\text{ mA}, V_{CE} = -20\text{ V}, f = 100\text{ MHz}$	200	-	MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{ V}, I_E = 0, f = 100\text{ kHz}$	-	8.0	pF
C_{ib}	Input Capacitance	$V_{EB} = -2.0\text{ V}, I_C = 0, f = 100\text{ kHz}$	-	30	pF

SWITCHING CHARACTERISTICS

t_{on}	Turn-On Time	$V_{CC} = -30\text{ V}, I_C = -150\text{ mA}, I_{B1} = -15\text{ mA}$	-	45	ns
t_d	Delay Time		-	10	ns
t_r	Rise Time		-	40	ns
t_{off}	Turn-Off Time	$V_{CC} = -6.0\text{ V}, I_C = -150\text{ mA}, I_{B1} = I_{B2} = -15\text{ mA}$	-	100	ns
t_s	Storage Time		-	80	ns
t_f	Fall Time		-	30	ns

4. Pulse test: pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2.0\%$.

ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping†
PN2907ABU	2907A	TO-92 3 4.825x4.76 (Pb-Free)	10000 Units / Bulk
PN2907ATF		TO-92 3 4.825x4.76 LEADFORMER (Pb-Free)	2000 / Tape & Reel
PN2907ATFR			2000 Units / Fan-Fold
PN2907ATA			
PN2907ATAR			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

TYPICAL PERFORMANCE CHARACTERISTICS

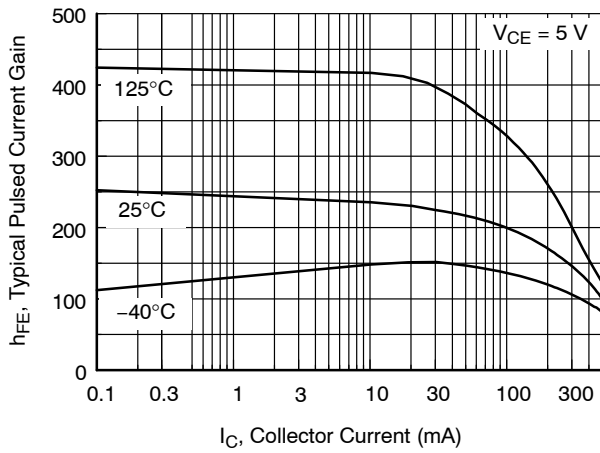


Figure 1. Typical Pulsed Current Gain vs. Collector Current

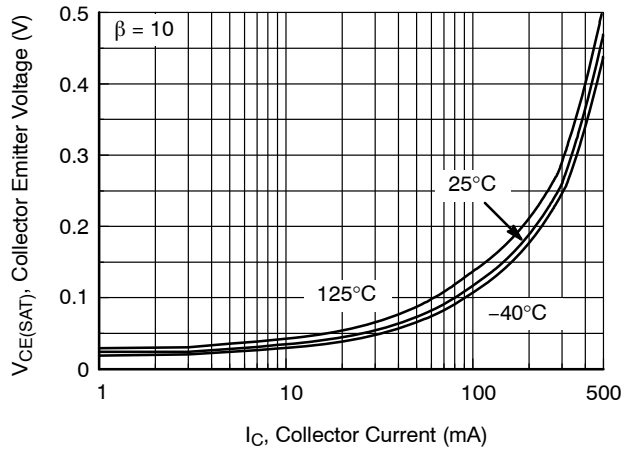


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

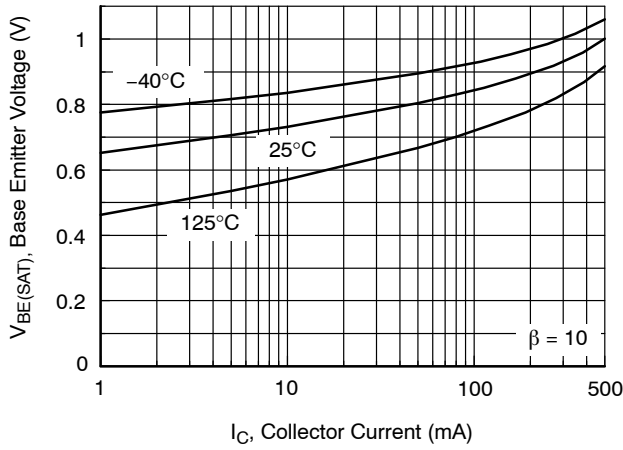


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

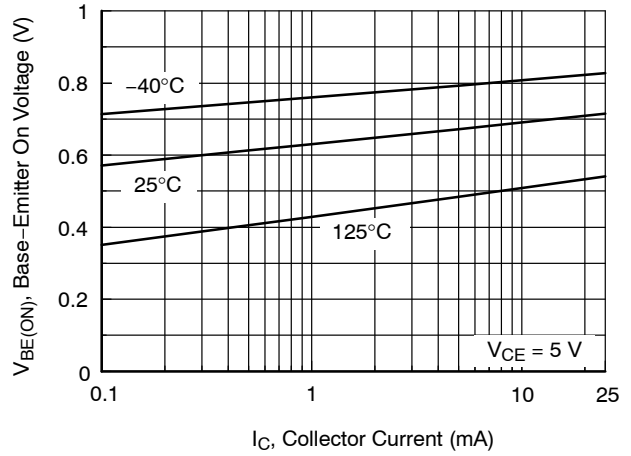


Figure 4. Base-Emitter On Voltage vs. Collector Current

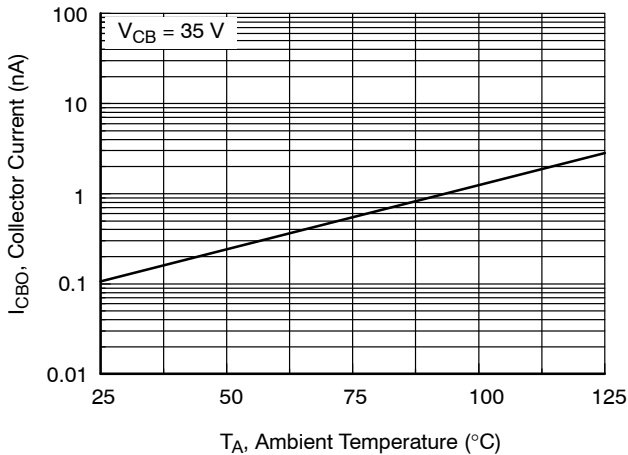


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

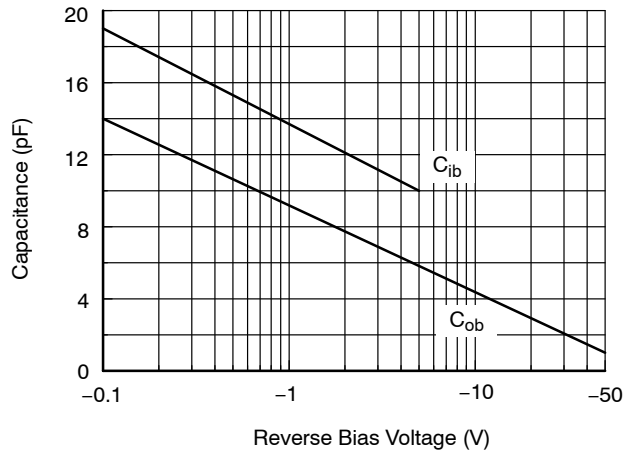


Figure 6. Input and Output Capacitance vs. Reverse Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

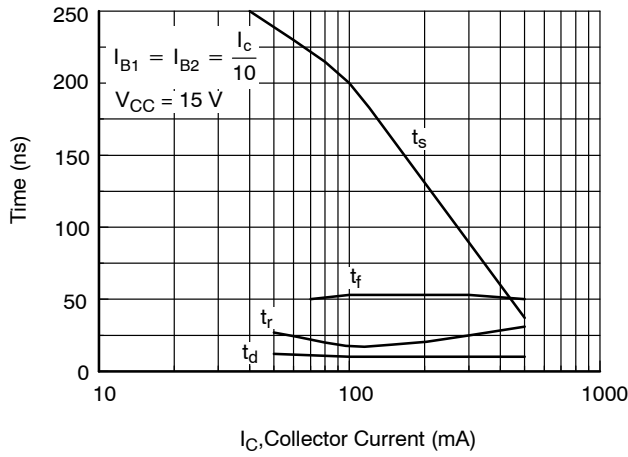


Figure 7. Switching Times vs. Collector Current

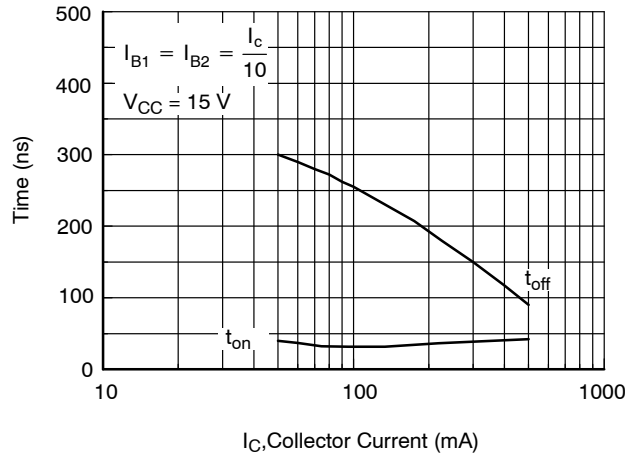


Figure 8. Turn-On and Turn-Off Times vs. Collector Current

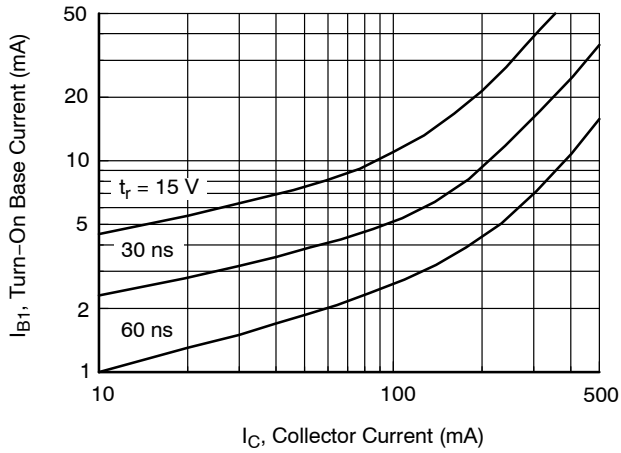


Figure 9. Rise Time vs. Collector and Turn-On Base Currents

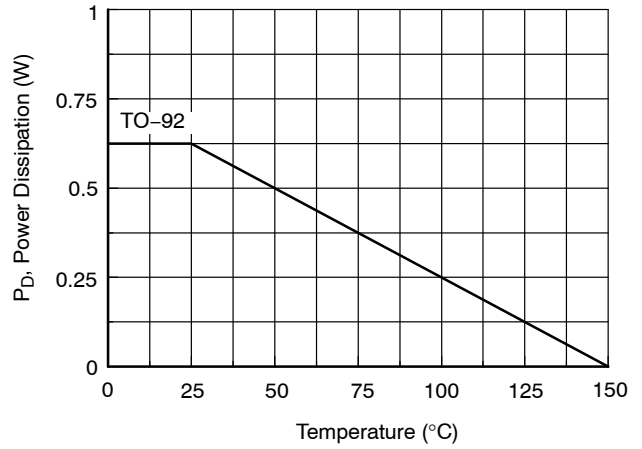


Figure 10. Power Dissipation vs. Ambient Temperature

TYPICAL PERFORMANCE CHARACTERISTICS (f = 1.0 kHz)

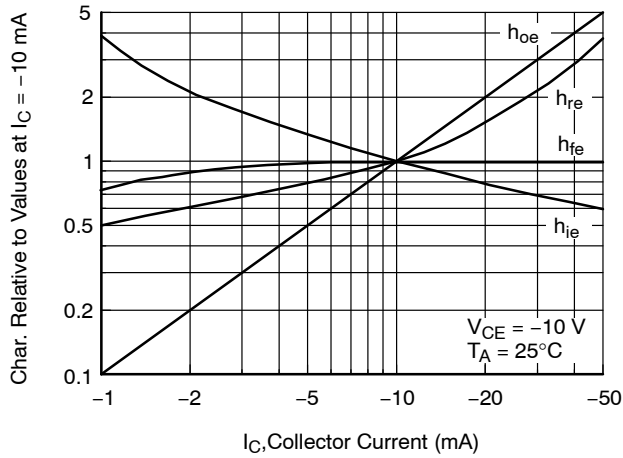


Figure 11. Common Emitter Characteristics

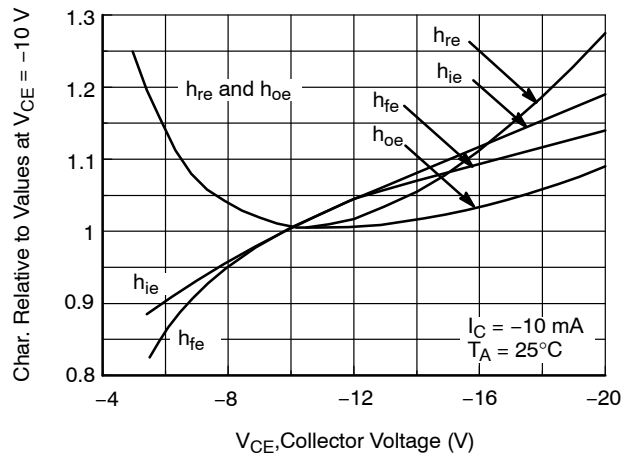


Figure 12. Common Emitter Characteristics

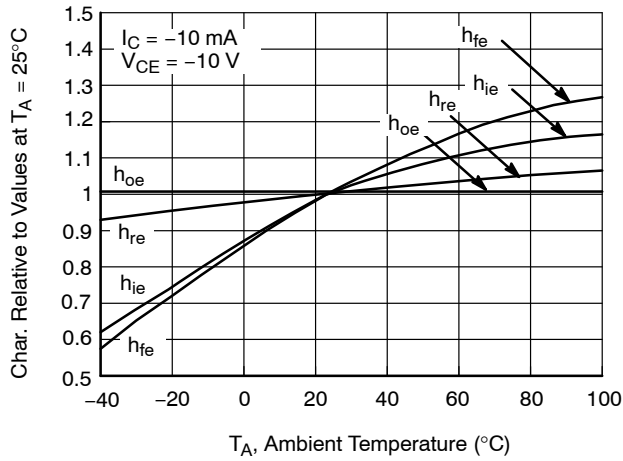
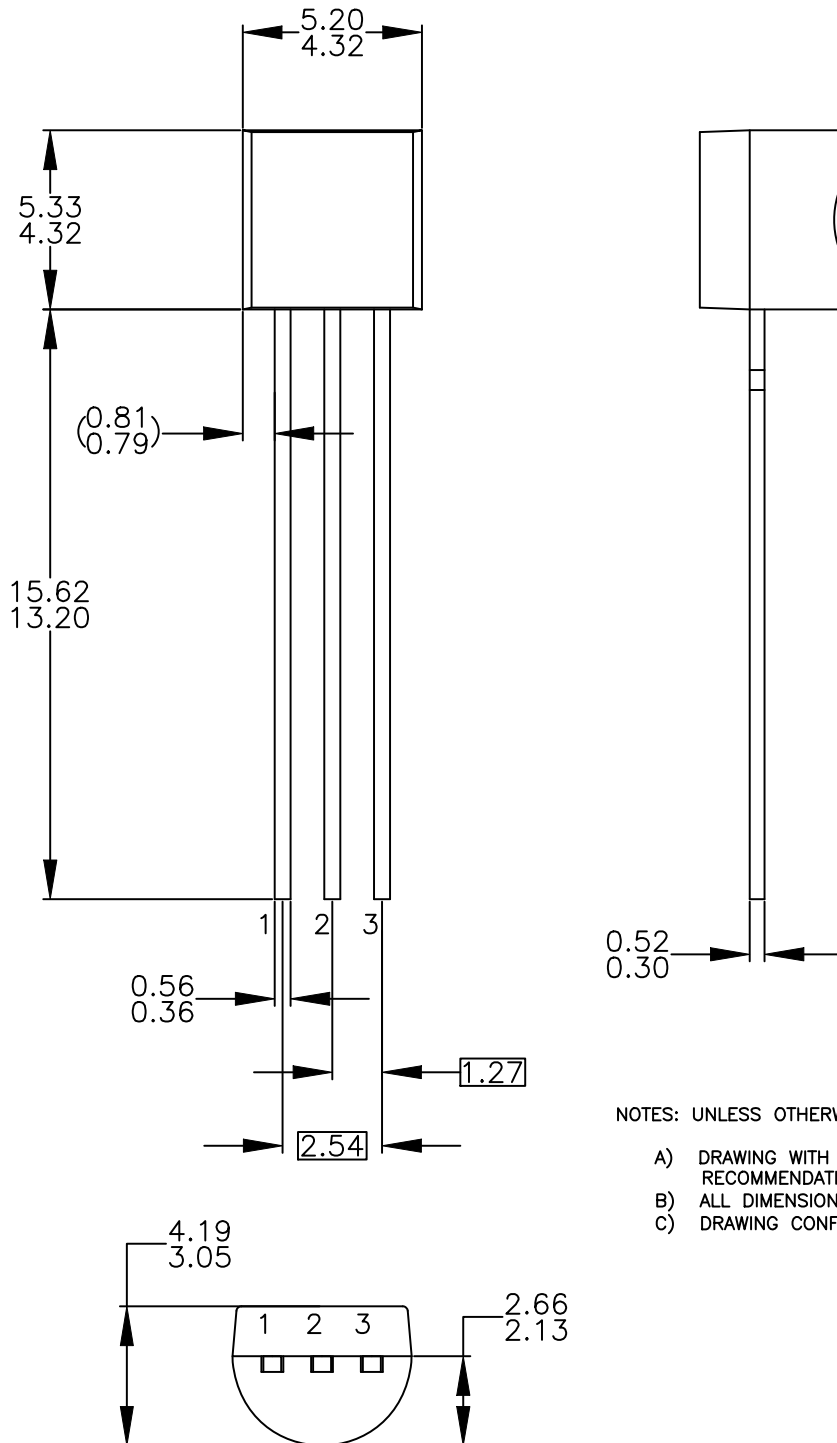


Figure 13. Common Emitter Characteristics

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

TO-92 3 4.825x4.76
CASE 135AN
ISSUE O

DATE 31 JUL 2016



NOTES: UNLESS OTHERWISE SPECIFIED

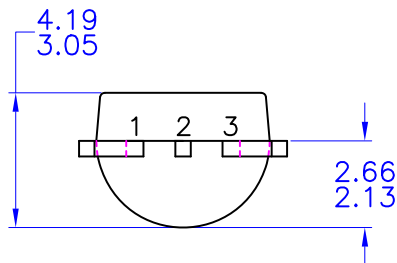
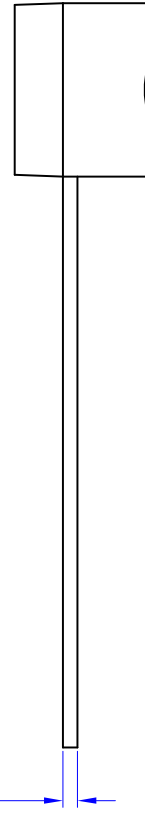
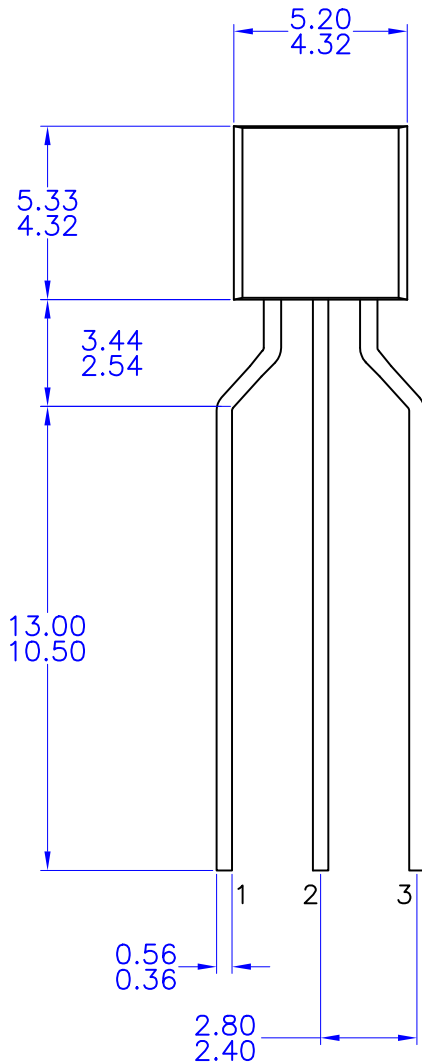
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